

## Description

MPT023N10-T, the N-channel Enhanced Power MOSFETs, is obtained by advanced double trench technology which reduce the conduction loss, improve switching performance and enhance the avalanche energy. This is suitable device for BMS and high current switching applications.

## KEY CHARACTERISTICS

Parameter	Value	Unit
$V_{DSS}$	100	V
$I_D$	326	A
$R_{DS(on),typ}$	1.4	$m\Omega$

## FEATURES

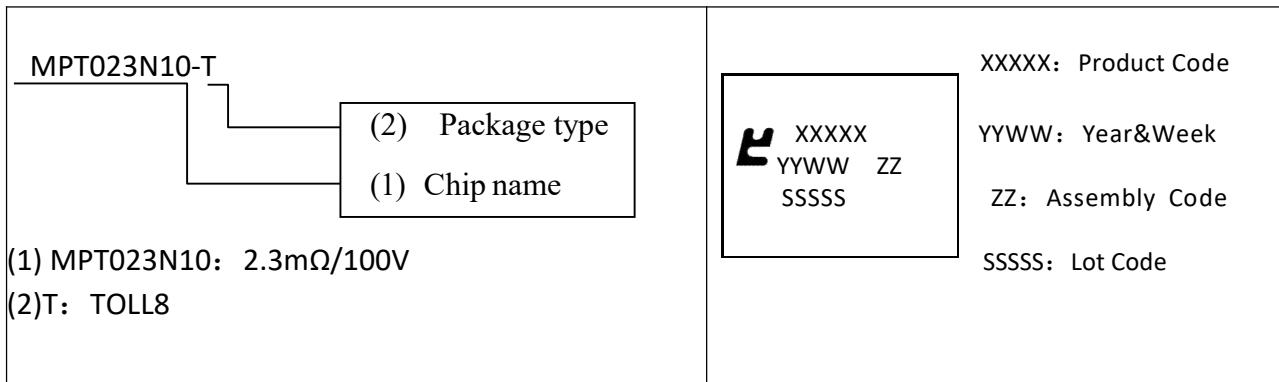
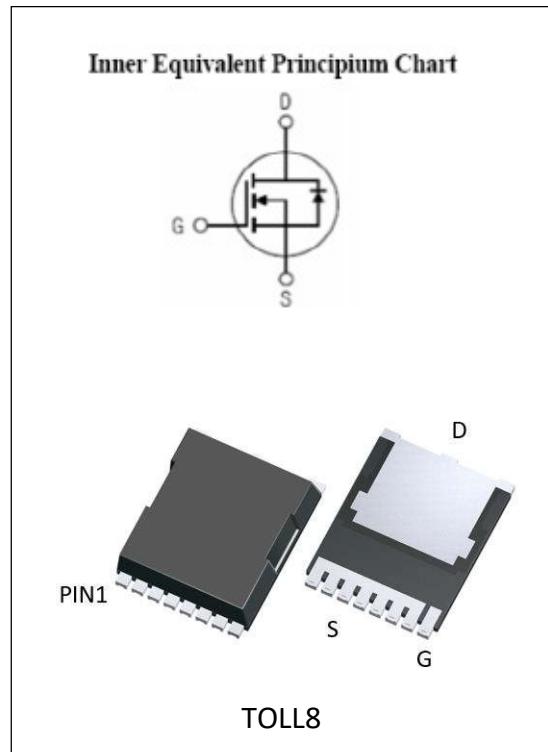
- ① Fast Switching
- ② Low On-Resistance
- ③ Low Gate Charge
- ④ Low Reverse transfer capacitances
- ⑤ High avalanche ruggedness
- ⑥ RoHS product

## APPLICATIONS

- ① BMS
- ② High current switching applications

## ORDERING INFORMATION

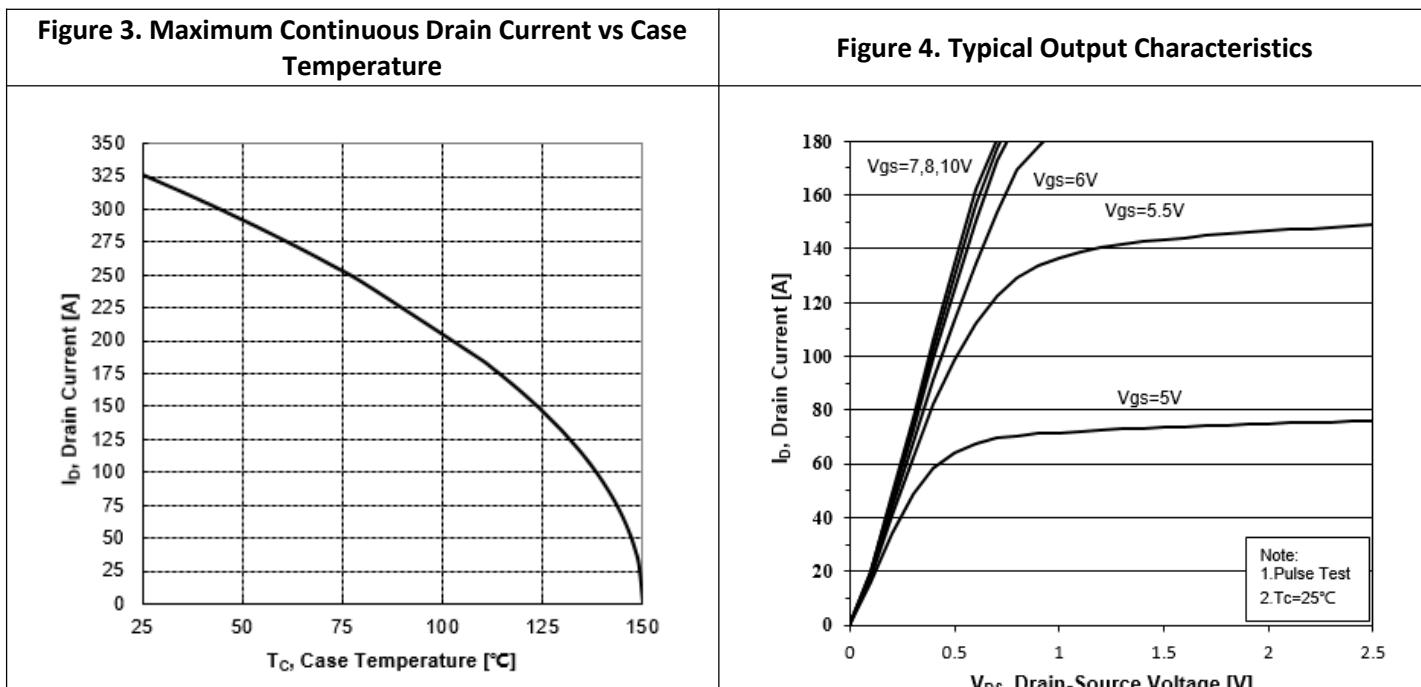
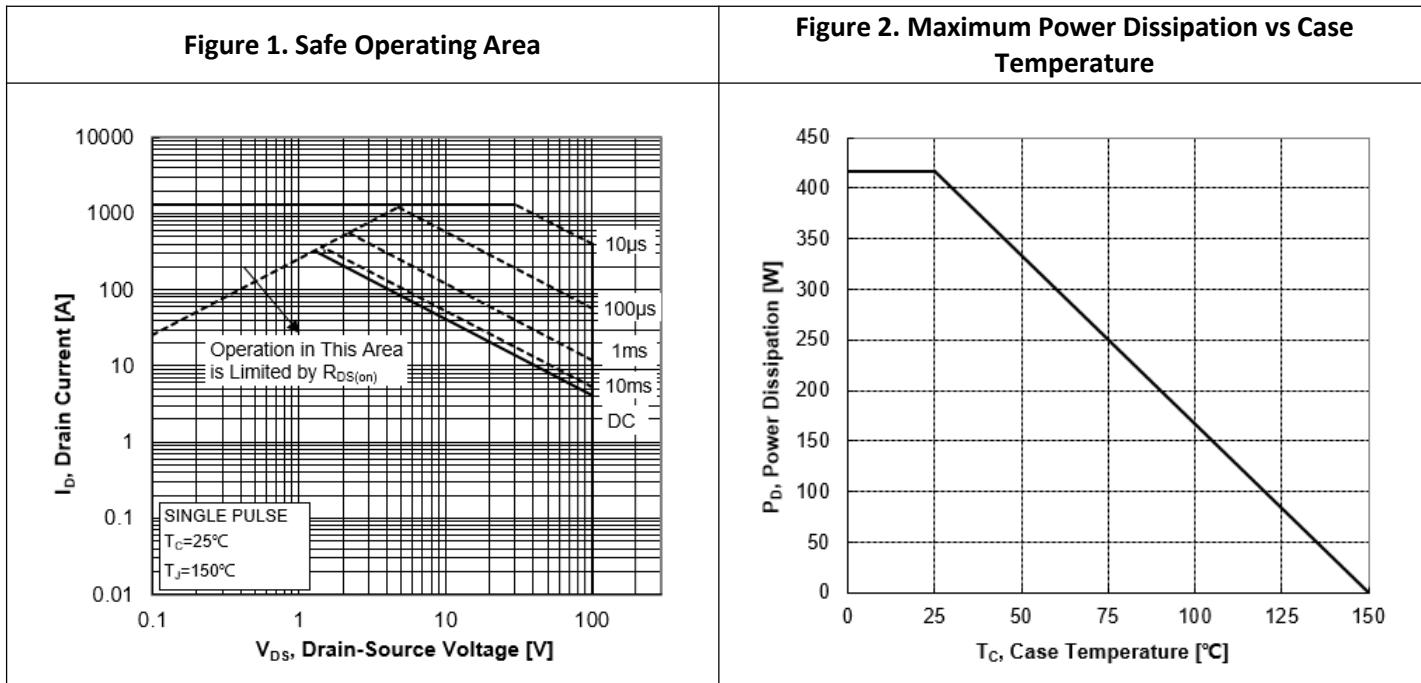
Ordering Codes	Package	Product Code	Packing
MPT023N10-T	TOLL8	MPT023N10-T	Reel

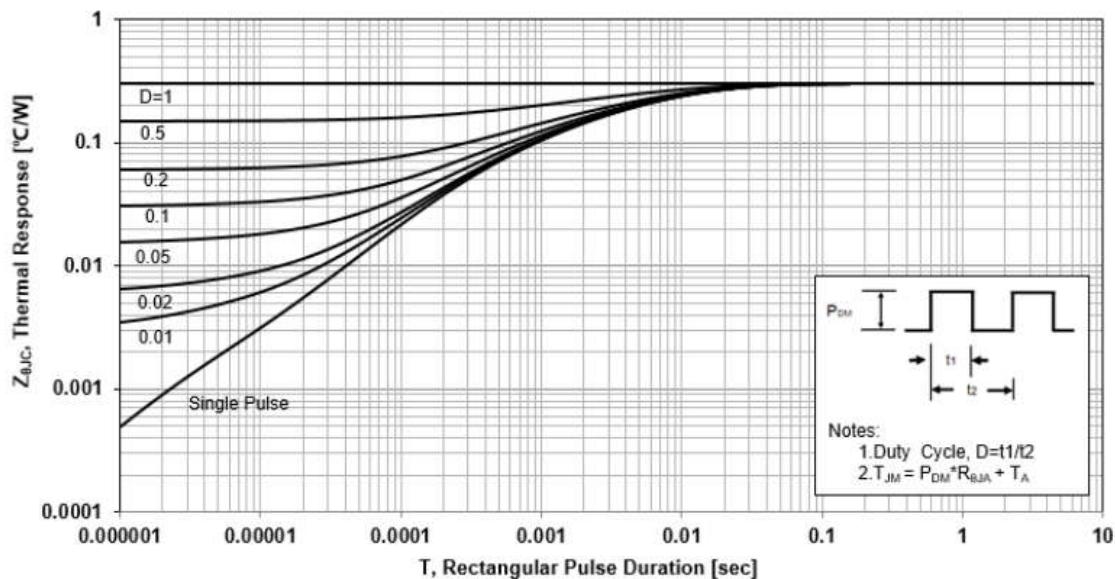
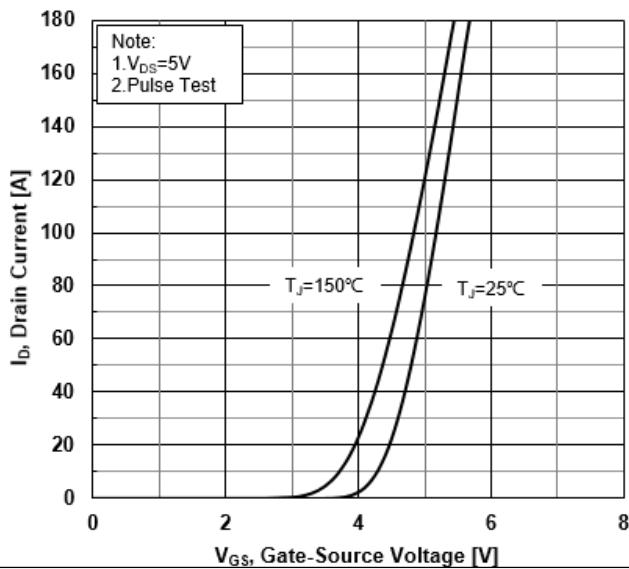
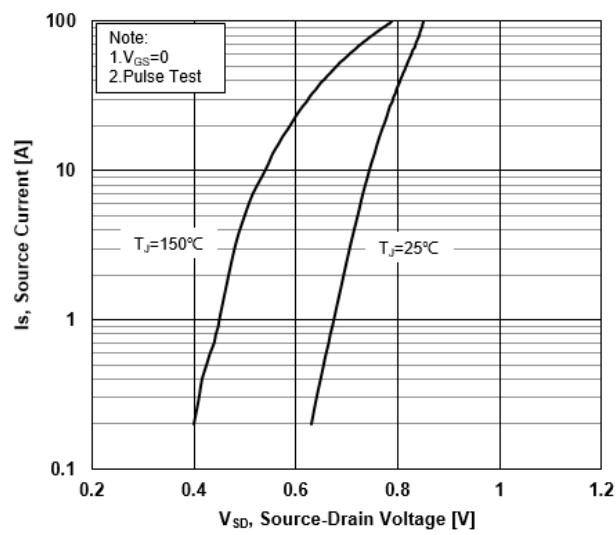






## Characteristics Curves



**Figure 5. Transient Thermal Impedance**

**Figure 6. Typical Transfer Characteristics**

**Figure 7. Source-Drain Diode Forward Characteristics**


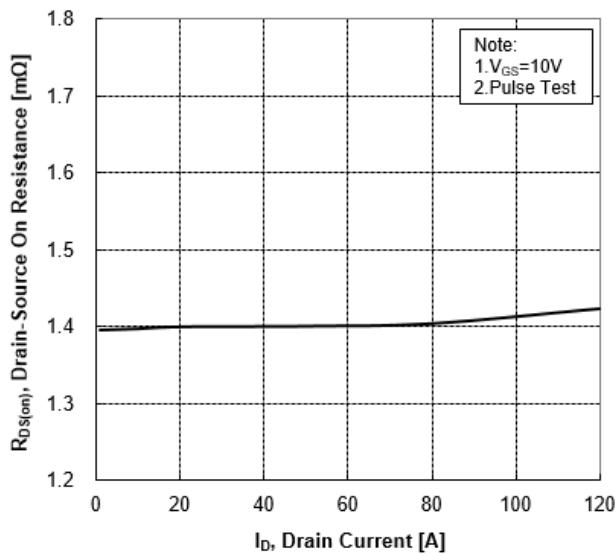
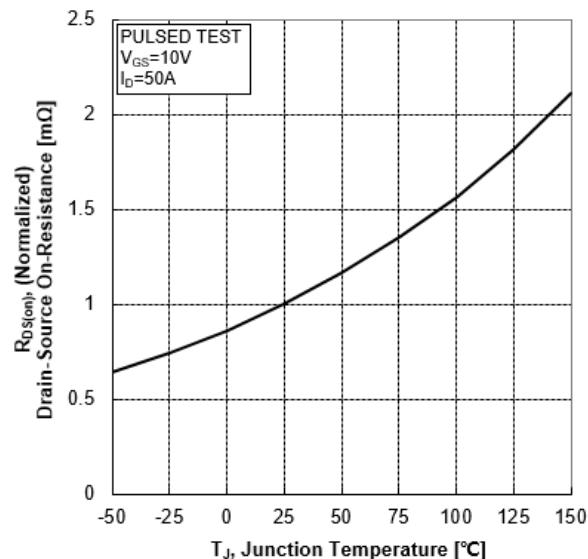
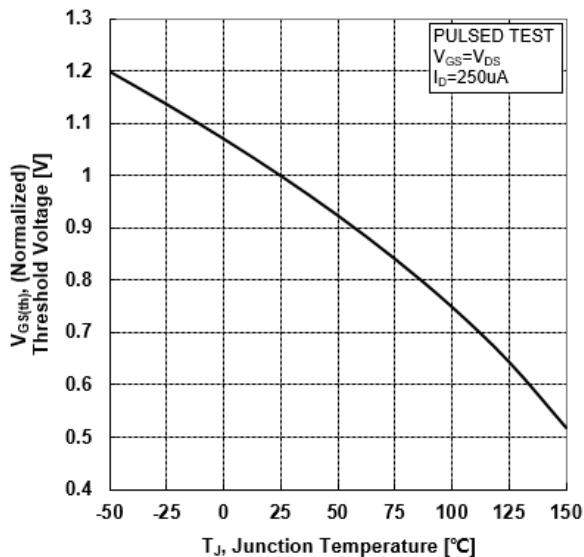
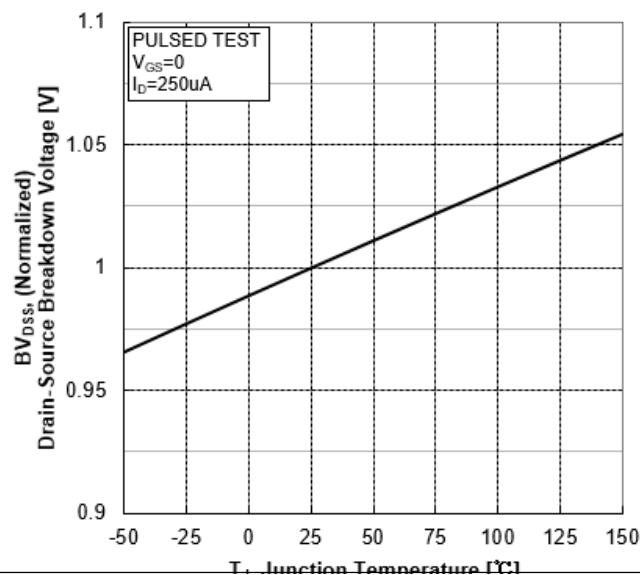
**Figure 8. Drain-Source On-Resistance vs Drain Current**

**Figure 9. Normalized On-Resistance vs Junction Temperature**

**Figure 10. Normalized Threshold Voltage vs Junction Temperature**

**Figure 11. Normalized Breakdown Voltage vs Junction Temperature**


Figure 12. Capacitance Characteristics

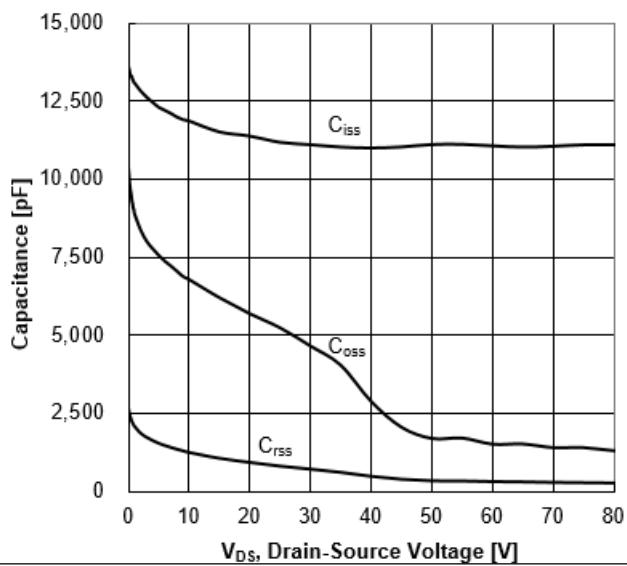
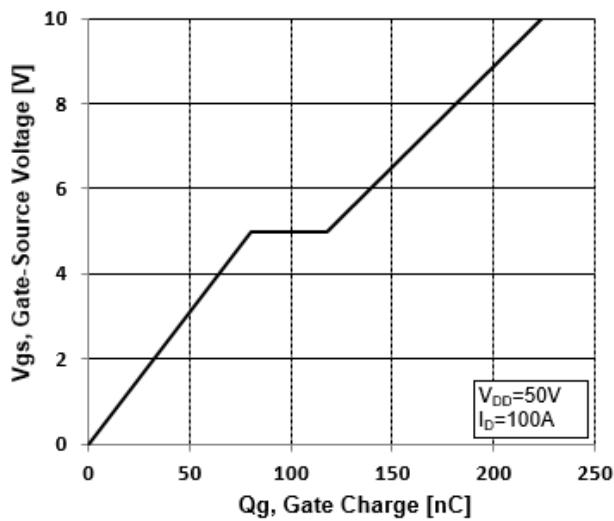
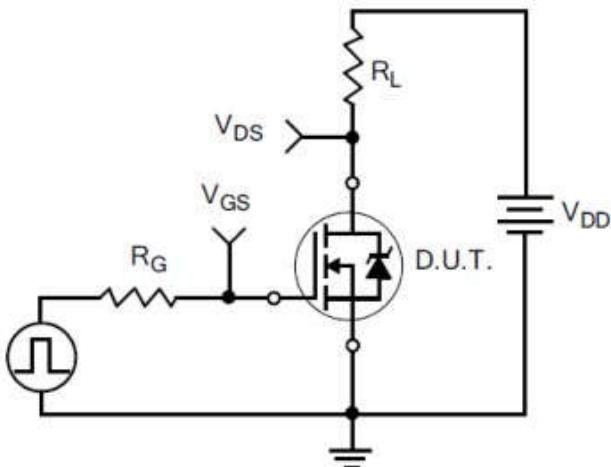


Figure 13. Typical Gate Charge vs Gate-Source Voltage

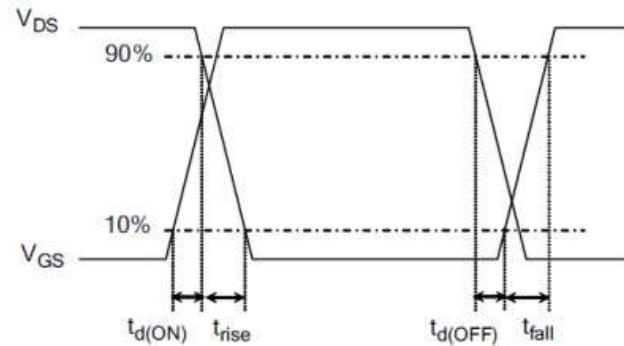


## Test Circuit and Waveform

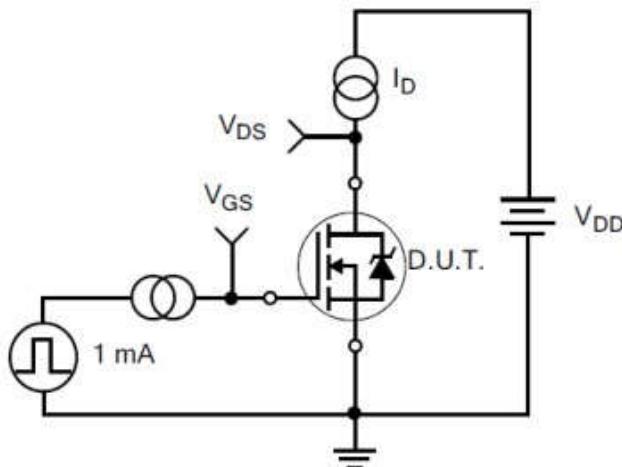
**Figure 14. Resistive Switching Test Circuit**



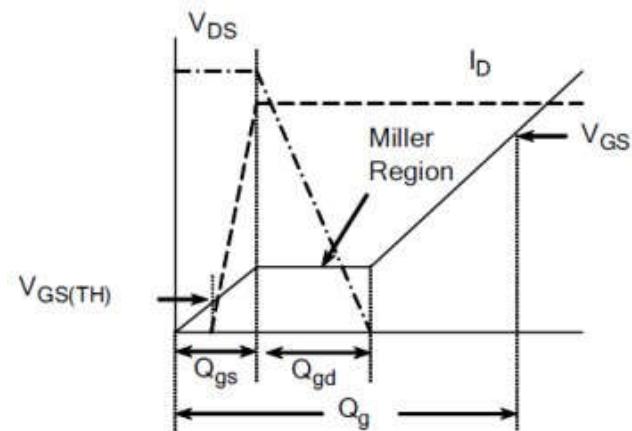
**Figure 15. Resistive Switching Waveforms**

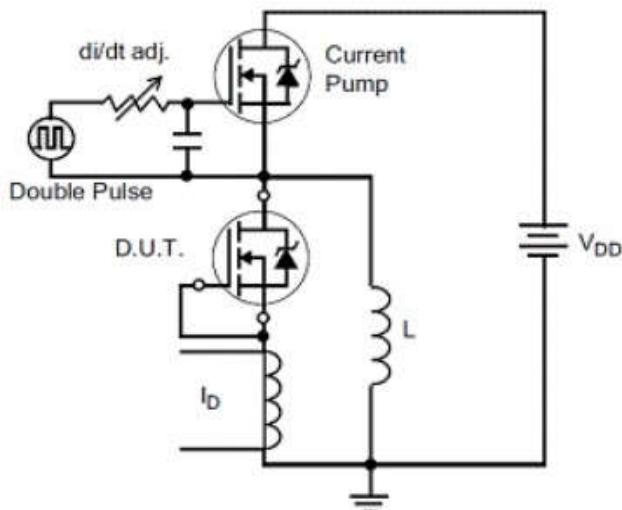
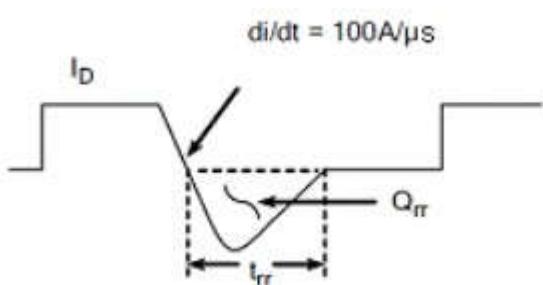
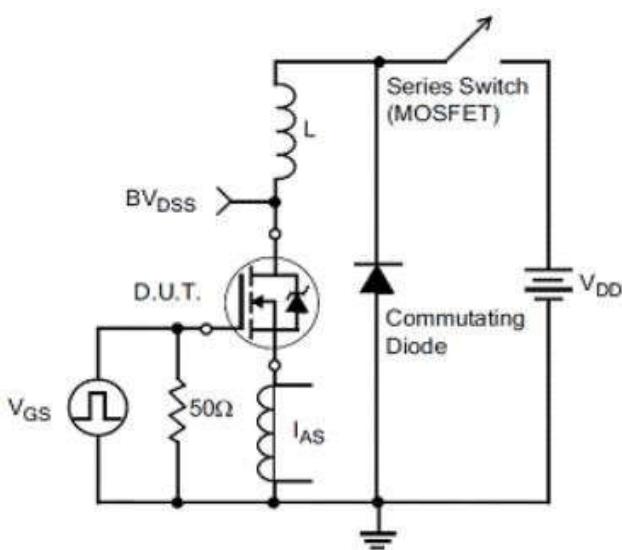
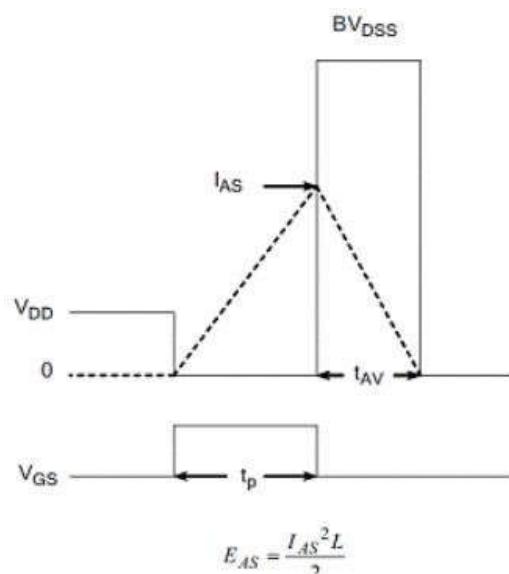


**Figure 16. Gate Charge Test Circuit**



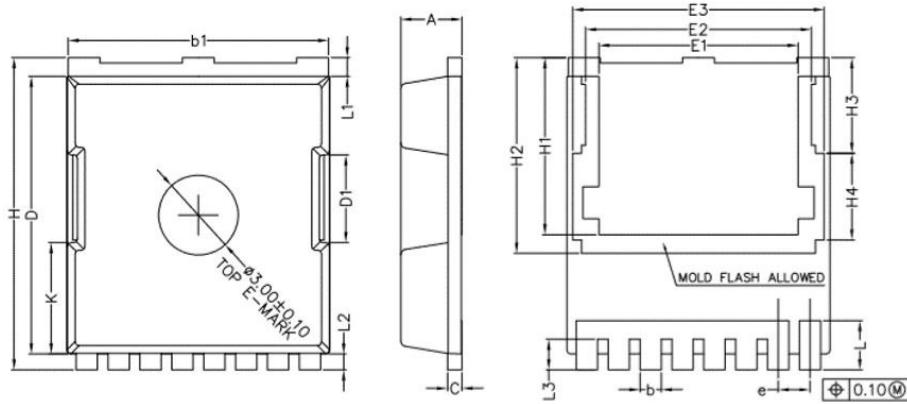
**Figure 17. Gate Charge Waveforms**



**Figure 18. Diode Reverse Recovery Test Circuit**

**Figure 19. Diode Reverse Recovery Waveform**

**Figure 20. Unclamped Inductive Switching Test Circuit**

**Figure 21. Unclamped Inductive Switching Waveform**


## Package Description

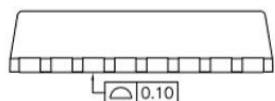
TOLL-8



TOP VIEW

SIDE VIEW

BOTTOM VIEW



SIDE VIEW

SYMBOL	MIN	NOM	MAX
A	2.20	2.30	2.40
b	0.70	0.80	0.90
b1	9.70	9.80	9.90
c	0.40	0.50	0.60
D	10.28	10.43	10.58
D1	3.15	3.30	3.45
E	9.70	9.90	10.10
E1	7.35	7.50	7.65
E2	8.35	8.50	8.65
E3	9.31	9.46	9.61
e	1.10	1.20	1.30
H	11.48	11.73	11.88
H1	6.55	6.65	6.75
H2	7.20	7.35	7.50
H3	3.44	3.59	3.74
H4	3.11	3.26	3.41
K	4.03	4.18	4.33
L	1.60	1.85	2.10
L1	0.55	0.70	0.85
L2	0.45	0.60	0.75
L3	1.00	1.15	1.30



迈诺斯科技

MPT023N10-T

**NOTE:**

1. Exceeding the maximum ratings of the device in performance may cause damage to the device, even the permanent failure, which may affect the dependability of the machine. Please do not exceed the absolute maximum ratings of the device when circuit designing.
2. When installing the heat sink, please pay attention to the torsional moment and the smoothness of the heat sink.
3. MOSFETs is the device which is sensitive to the static electricity, it is necessary to protect the device from being damaged by the static electricity when using it.
4. Shenzhen Minos reserves the right to make changes in this specification sheet and is subject to change without prior notice.

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